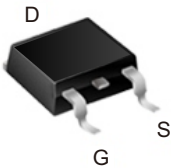


ACMS50P06D-HF

P-Channel
RoHS Device
Halogen Free

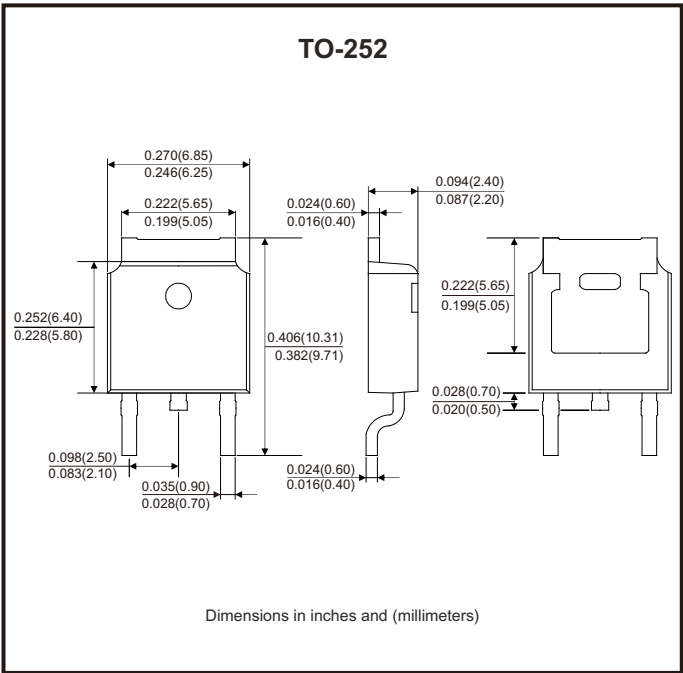


Features

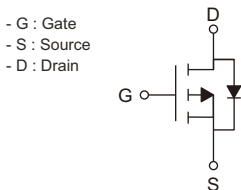
- Low $R_{DS(ON)}$.
- 100% unclamped inductive switching.
- AEC-Q101 Qualified.

Mechanical data

- Case: TO-252, molded plastic.
- Molding compound: UL flammability classification rating 94V-0.
- Terminals: Matte tin-plated leads, solderable per MIL-STD-202, method 208.



Circuit Diagram



Maximum Ratings (at $T_C=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	-60	V
Gate-source voltage	V_{GS}	± 20	V
Continuous drain current (Note 1)	I_D	-50	A
Pulsed drain current (Note 1)	I_{DM}	-200	
Power dissipation (Note 2)	P_D	125	W
Thermal resistance junction to case	$R_{\theta JC}$	1	$^{\circ}\text{C/W}$
Operating junction temperature range	T_J	-55 to +150	$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics (at $T_c=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{DSS}	V _{GS} = 0V, I _D = -250μA	-60			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = -48V, V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
On Characteristics (Note 3)						
Static drain-source on-resistance	R _{DS(on)}	V _{GS} = -10V, I _D = -15A			50	mΩ
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-1		-3	V
Dynamic Characteristics						
Input capacitance	C _{iss}	V _{GS} = 0V, V _{DS} = -30V, f = 1MHz		3129		pF
Output capacitance	C _{oss}			173		
Reverse transfer capacitance	C _{rss}			162.6		
Switching Characteristics						
Turn-on delay time	t _{d(on)}	V _{DD} = -30V, V _{GS} = -10V R _G = 3Ω		13		ns
Turn-on rise time	t _r			17		
Turn-off delay time	t _{d(off)}			50		
Turn-off fall time	t _f			20		
Total gate charge	Q _g	V _{DD} = -30V, I _D = -15A, V _{GS} = -10V		53		nC
Gate to source charge	Q _{gs}			15		
Gate to drain (miller) charge	Q _{gd}			13		
Source-Drain Diode Characteristics						
Diode forward voltage	V _{SD}	I _{SD} = -15A, V _{GS} = 0V			-1.2	V

- Notes: 1. The maximum current rating is limited by package. And device mounted on a large heatsink.
 2. The power dissipation PD is limited by $T_{\text{J(MAX)}}=150^{\circ}\text{C}$. And device mounted on a large heatsink
 3. The data tested by pulsed, pulse width $\leq 380\mu\text{s}$, duty cycle $\leq 2\%$.

Rating and Characteristic Curves (ACMS50P06D-HF)

Fig.1 - Typical Output Characteristics

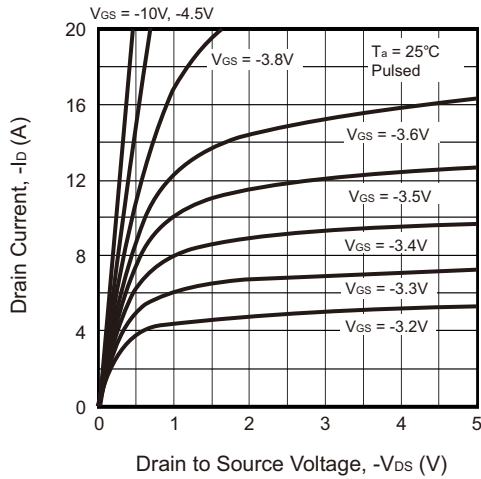


Fig.2 - On-Resistance vs. Continuous Drain Current

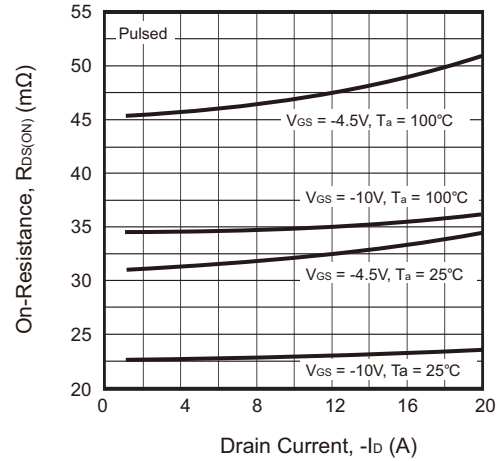


Fig.3 - On-Resistance vs. Gate-Source Voltage

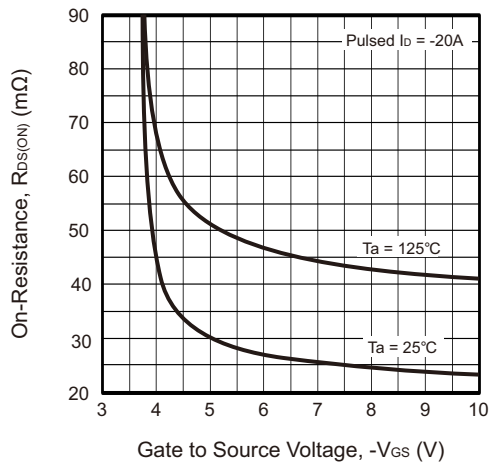


Fig.4 - Body-Diode Characteristics

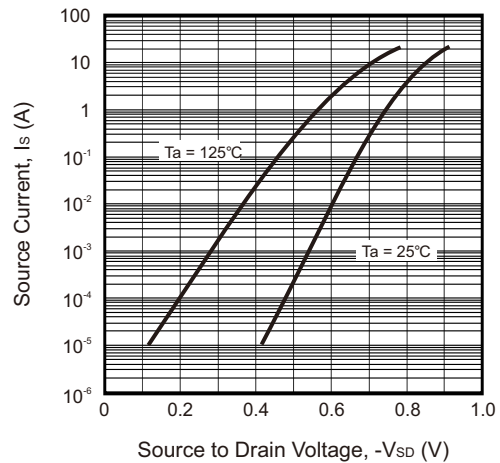


Fig.5 - Gate Threshold Voltage vs. Junction Temperature

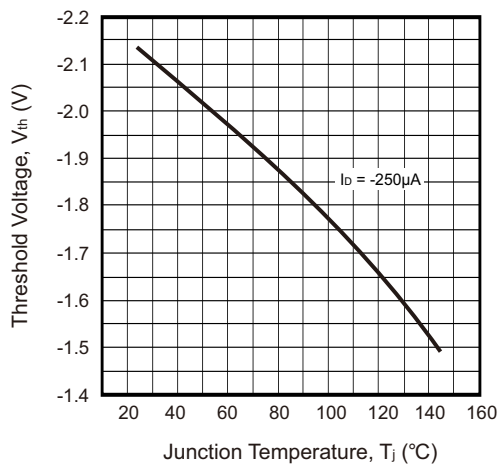
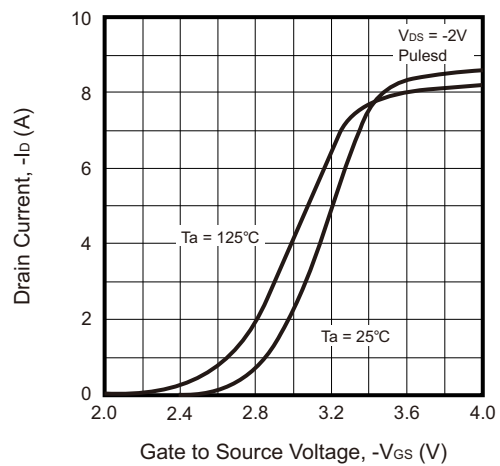
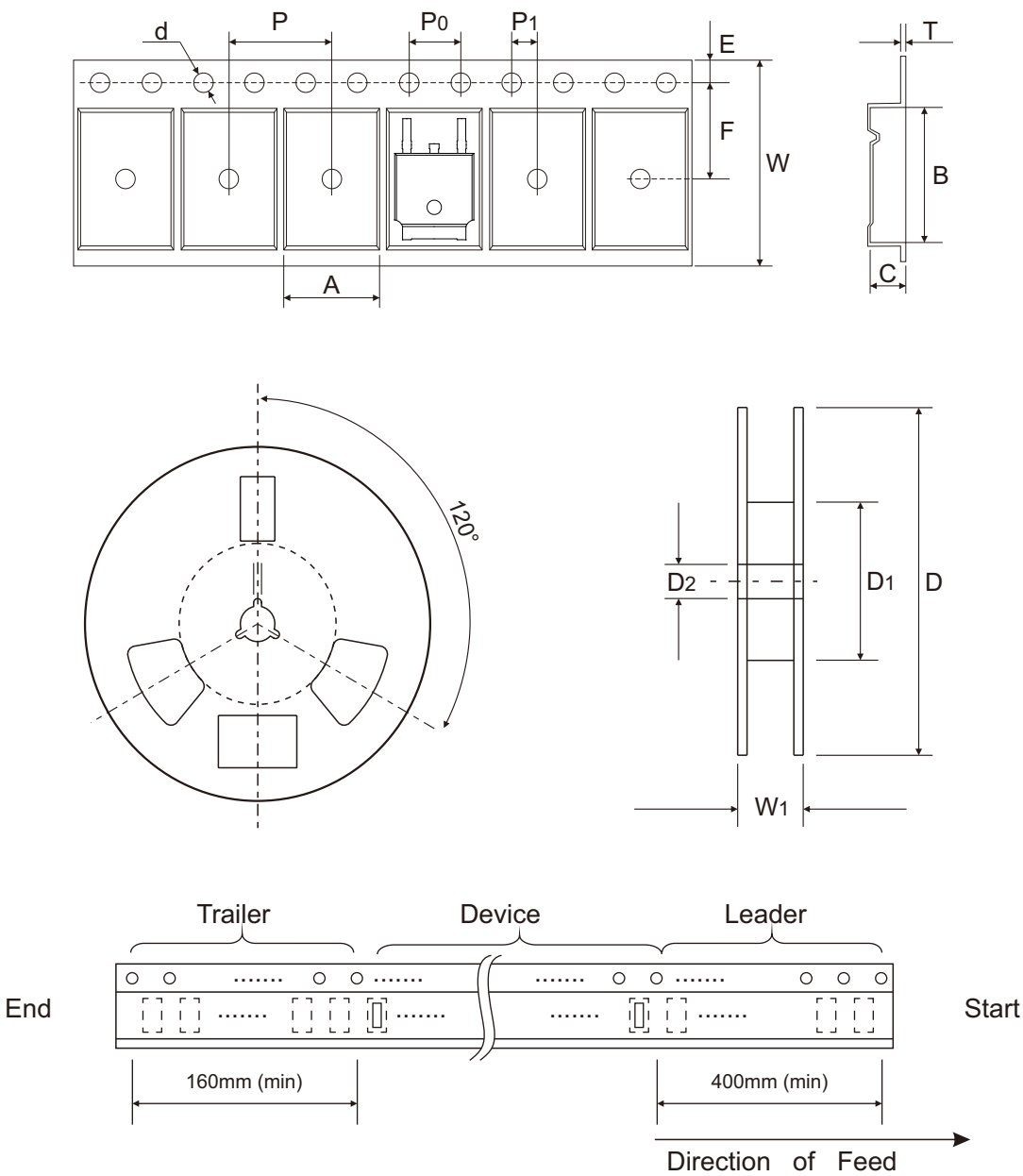


Fig.6 - Transfer Characteristics



Reel Taping Specification

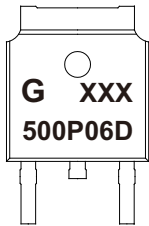


TO-252	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	6.90 ± 0.10	10.50 ± 0.10	2.70 ± 0.10	1.50 ± 0.25	330 ± 1.00	100 ± 1.00	13.00 ± 0.20
	(inch)	0.272 ± 0.004	0.413 ± 0.004	0.106 ± 0.004	0.059 ± 0.010	12.992 ± 0.039	3.937 ± 0.039	0.512 ± 0.008

TO-252	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	7.50 ± 0.10	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	0.30 ± 0.05	16.00 ± 0.30 $- 0.20$	21.00 ± 0.30
	(inch)	0.069 ± 0.004	0.295 ± 0.004	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.012 ± 0.002	0.630 ± 0.012 $- 0.008$	0.827 ± 0.012

Marking Code

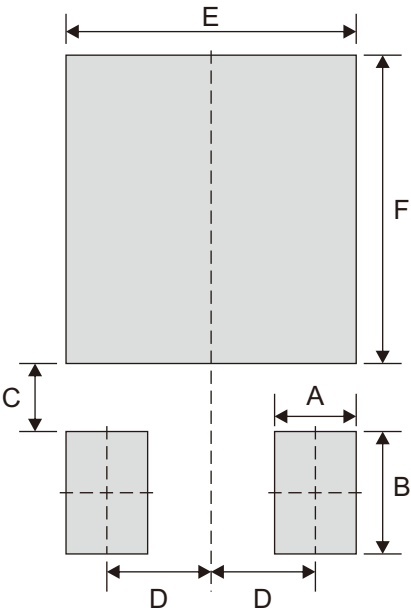
Part Number	Marking Code
ACMS50P06D-HF	500P06D



XXX = Control code

Suggested P.C.B. PAD Layout

SIZE	TO-252	
	(mm)	(inch)
A	1.80	0.071
B	2.70	0.106
C	1.50	0.059
D	2.30	0.091
E	6.40	0.252
F	6.80	0.268



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
TO-252	2,500	13